## TS5A23166 0.9-@ Dual-SPST Analog Switch 5-V and 3.3-V 2-Channel Analog Switch

## 1 Features

- Isolation in Powered-Down Mode, $\mathrm{V}_{+}=0$
- Low ON-state resistance (0.9 $\Omega$ )
- Control inputs are 5.5-V Tolerant
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion (THD)
- $1.65-\mathrm{V}$ to $5.5-\mathrm{V}$ Single-supply operation
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD Performance tested per JESD 22
- 2000-V Human-body model (A114-B, Class II)
- 1000-V Charged-device model (C101)


## 3 Description

The TS5A23166 device is a dual single-pole singlethrow (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V . The TS5A23166 device offers a low ON-state resistance and an excellent channel-to-channel ON-state resistance matching. The TS5A23166 device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

| Device Information ${ }^{(1)}$ |  |
| :--- | :---: |
| PART NUMBER PACKAGE BODY SIZE (NOM) <br> TS5A23166 VSSOP (8) $2.30 \mathrm{~mm} \times 2.00 \mathrm{~mm}$ <br>  DSBGA (8) $1.91 \mathrm{~mm} \times 0.91 \mathrm{~mm}$ |  |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## 2 Applications

- Cell phones
- Portable instrumentation
- Audio and video signal routing
- Low-voltage data-acquisition systems
- Communication circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Terminals and Peripherals


## Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

## Table of Contents

1 Features ..... 1
2 Applications ..... 1
3 Description ..... 1
4 Revision History. ..... 2
5 Pin Configuration and Functions ..... 3
6 Specifications ..... 3
6.1 Absolute Maximum Ratings ..... 3
6.2 ESD Ratings ..... 4
6.3 Recommended Operating Conditions ..... 4
6.4 Thermal Information ..... 4
6.5 Electrical Characteristics: 5-V Supply ..... 4
6.6 Electrical Characteristics: 3.3-V Supply ..... 6
6.7 Electrical Characteristics: 2.5-V Supply ..... 7
6.8 Electrical Characteristics: 1.8-V Supply ..... 9
6.9 Switching Characteristics: 5-V Supply ..... 10
6.10 Switching Characteristics: 3.3-V Supply ..... 10
6.11 Switching Characteristics: 2.5-V Supply ..... 10
6.12 Switching Characteristics: 1.8-V Supply ..... 11
6.13 Typical Characteristics ..... 12
7 Parameter Measurement Information ..... 14
8 Detailed Description ..... 18
8.1 Overview ..... 18
8.2 Functional Block Diagram ..... 18
8.3 Feature Description ..... 18
8.4 Device Functional Modes ..... 18
9 Application and Implementation ..... 19
9.1 Application Information ..... 19
9.2 Typical Application ..... 19
10 Power Supply Recommendations ..... 20
11 Layout. ..... 20
11.1 Layout Guidelines ..... 20
11.2 Layout Example ..... 20
12 Device and Documentation Support ..... 21
12.1 Device Support. ..... 21
12.2 Receiving Notification of Documentation Updates ..... 22
12.3 Community Resources ..... 22
12.4 Trademarks ..... 22
12.5 Electrostatic Discharge Caution. ..... 22
12.6 Glossary ..... 22
13 Mechanical, Packaging, and Orderable Information ..... 22

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.
Changes from Revision I (March 2018) to Revision J Page

- Changed the Thermal Information table ..... 4
Changes from Revision H (May 2015) to Revision I Page
- Added Note: "Not tested in production" to leakage current at $25^{\circ} \mathrm{C}$ in the Electrical Characteristics tables ..... 4
Changes from Revision G (February 2013) to Revision H ..... Page
- Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ..... 1
- Updated document to new TI data sheet format - no specification changes. ..... 1
- Removed Ordering Information table. ..... 1
Changes from Revision F (September 2012) to Revision G Page
- Changed pin numbers for YZT or YZP package pinout. ..... 3


## 5 Pin Configuration and Functions



Pin Functions

| PIN |  |  | TYPE |  |
| :--- | :---: | :---: | :---: | :--- |
| NAME | TSSOP NO. | DSBGA NO. |  |  |
| COM1 | 2 | B1 | I/O | Common port for switch 1 |
| COM2 | 6 | C2 | I/O | Common port for switch 2 |
| GND | 4 | D1 | GND | Ground |
| IN1 | 7 | B2 | I | Active-high control pin connecting NO1 to COM1. |
| IN2 | 3 | C1 | I | Active-high control pin connecting NO2 to COM2. |
| NO1 | 1 | A1 | I/O | Normally open switch path 1 |
| NO2 | 5 | D2 | I/O | Normally open switch path 2 |
| V+ | 8 | A2 | PWR | Power supply pin |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ${ }^{(1)(2)}$

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{+}$ | Supply voltage ${ }^{(3)}$ |  | -0.5 | 6.5 | V |
| $\mathrm{V}_{\mathrm{NO}}$ <br> $\mathrm{V}_{\text {сом }}$ | Analog voltage ${ }^{(3)(4)(5)}$ |  | -0.5 | $\mathrm{V}_{+}+0.5$ | V |
| $\mathrm{I}_{\mathrm{K}}$ | Analog port diode current | $\mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\text {COM }}<0$ | -50 |  | mA |
| $\mathrm{I}_{\mathrm{NO}}$ | ON-state switch current | $\mathrm{V}_{\mathrm{NO},} \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{+}$ | -200 | 200 | mA |
| $\mathrm{I}_{\text {com }}$ | ON-state peak switch current ${ }^{(6)}$ | $\mathrm{V}_{\mathrm{NO},} \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{+}$ | -400 | 400 | mA |
| $\mathrm{V}_{1}$ | Digital input voltage ${ }^{(3)(4)}$ |  | -0.5 | 6.5 | V |
| $\mathrm{I}_{\mathrm{K}}$ | Digital input clamp current | $\mathrm{V}_{1}<0$ | -50 |  | mA |
| $\mathrm{I}_{+}$ | Continuous current through $\mathrm{V}_{+}$ |  |  | 100 | mA |
| $\mathrm{I}_{\text {GND }}$ | Continuous current through GND |  | -100 | 100 | mA |

[^0]
### 6.2 ESD Ratings

| $\mathrm{V}_{(\text {ESD })} \quad$ Electrostatic discharge |  |  | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ${ }^{(1)}$ |
| :--- | :--- | :---: | :---: |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|  |  | MIN | MAX | UNIT |
| :--- | :--- | ---: | :---: | :---: |
| $\mathrm{V}_{\text {IO }}$ | Input/output voltage | 0 | $\mathrm{~V}_{+}$ | V |
| $\mathrm{V}_{+}$ | Supply voltage | 1.65 | 5.5 | V |
| $\mathrm{~V}_{1}$ | Control Input Voltage | 0 | 5.5 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating free-air temperature | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |

### 6.4 Thermal Information

| THERMAL METRIC ${ }^{(1)}$ |  | TS5A23166 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | DCU (VSSOP) | YZP (DSBGA) | YZT (DSBGA) |  |
|  |  | 8 PINS | 8 PINS | 8 PINS |  |
| $\mathrm{R}_{\theta \mathrm{JA}}$ | Junction-to-ambient thermal resistance | 212.2 | 99.9 | 99.7 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өJC(top) }}$ | Junction-to-case (top) thermal resistance | 77.6 | 1.0 | 1.4 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\theta \mathrm{JB}}$ | Junction-to-board thermal resistance | 91.7 | 27.8 | 27.8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\varphi_{\text {JT }}$ | Junction-to-top characterization parameter | 7.1 | 0.4 | 0.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\varphi$ JB | Junction-to-board characterization parameter | 91.1 | 27.8 | 27.7 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report.

### 6.5 Electrical Characteristics: 5-V Supply

$\mathrm{V}_{+}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {сом }}$ $\mathrm{V}_{\mathrm{NO}}$ | Analog signal |  |  |  |  | 0 |  | $\mathrm{V}_{+}$ | V |
| $\mathrm{r}_{\text {peak }}$ | Peak ON resistance | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.9 | 1.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1.2 |  |
| $\mathrm{r}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.75 | 0.9 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1 |  |
| $\Delta r_{\text {on }}$ | ON-state resistance match between channels | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.04 | 0.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.1 |  |
| $\mathrm{r}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 4.5 V |  | 0.2 |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, 1.5 \mathrm{~V}, 2.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ |  |  | 0.15 | 0.25 |  |
|  |  |  |  | Full |  |  |  | 0.25 |  |
| $\mathrm{I}_{\text {NO(OFF) }}$ | NO OFF leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=4.5 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}}=4.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=1 \mathrm{~V}, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 5.5 V | 0 V | 4 | $20^{(2)}$ | nA |
|  |  |  |  | Full |  | -150 |  | 150 |  |
| $\mathrm{I}_{\text {NO(PWROFF) }}$ |  | $\mathrm{V}_{\mathrm{NO}}=0$ to 5.5 V , <br> $\mathrm{V}_{\text {Сом }}=5.5 \mathrm{~V}$ to 0 , | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 0 V | -10 | 0.2 | $10^{(2)}$ | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  | -50 |  | 50 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
(2) Not tested in production.

## Electrical Characteristics: 5-V Supply (continued)

$\mathrm{V}_{+}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

(3) All unused digital inputs of the device must be held at $\mathrm{V}_{+}$or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### 6.6 Electrical Characteristics: 3.3-V Supply

$\mathrm{V}_{+}=3 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {сом }}$ $\mathrm{V}_{\mathrm{NO}}$ | Analog signal range |  |  |  |  | 0 |  | $\mathrm{V}_{+}$ | V |
| $\mathrm{r}_{\text {peak }}$ | Peak ON resistance | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 3 V |  | 1.3 | 1.6 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1.8 |  |
| $r_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 3 V |  | 1.1 | 1.5 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 1.7 |  |
| $\Delta r_{\text {on }}$ | ON-state resistance match between channels | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 3 V |  | 0.04 | 0.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.1 |  |
| $\mathrm{r}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA} \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 3 V |  | 0.3 |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ |  |  | 0.15 | 0.25 |  |
|  |  |  |  | Full |  |  |  | 0.25 |  |
|  | NO OFF leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=1 \mathrm{~V}, \end{aligned}$ | Switch OFF, <br> see Figure 12 | $25^{\circ} \mathrm{C}$ | 3.6 V | -5 | 0.5 | $5^{(2)}$ | nA |
| INO(OFF) |  |  |  | Full |  | -50 |  | 50 |  |
| $\mathrm{I}_{\text {NO(PWROFF) }}$ |  | $\mathrm{V}_{\mathrm{NO}}=0$ to 3.6 V , <br> $\mathrm{V}_{\text {COM }}=3.6 \mathrm{~V}$ to 0 , | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 0 V | -5 | 0.1 | $5^{(2)}$ | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  | -25 |  | 25 |  |
| $\mathrm{I}_{\text {Com(OFF) }}$ | COM <br> OFF leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=1 \mathrm{~V}, \mathrm{~V}_{\mathrm{NO}}=3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{COM}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{NO}}=1 \mathrm{~V}, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 3.6 V | -5 | 0.5 | $5^{(2)}$ | nA |
|  |  |  |  | Full |  | -50 |  | 50 |  |
| ICOM(PWROFF) |  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=0 \text { to } 3.6 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{NO}}=3.6 \mathrm{~V} \text { to } 0, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 0 V | -5 | 0.1 | $5^{(2)}$ | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  | -25 |  | 25 |  |
|  |  | $\begin{array}{ll} \mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, & \\ \mathrm{~V}_{\mathrm{COM}}=\text { Open, } & \text { Switch ON, } \\ \text { or } & \text { see Figure } 13 \\ \mathrm{~V}_{\mathrm{NO}}=3 \mathrm{~V}, & \\ \mathrm{~V}_{\mathrm{COM}}=\text { Open, } & \\ \hline \end{array}$ |  | $25^{\circ} \mathrm{C}$ | 3.6 V | -2 | 0.3 | $2^{(2)}$ | nA |
| $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$ | ON leakage current |  |  | Full |  | -20 |  | 20 |  |
|  | COM <br> ON leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=1 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{NO}}=\mathrm{Open}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{COM}}=3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{NO}}=\text { Open, } \end{aligned}$ | Switch ON, see Figure 13 | $25^{\circ} \mathrm{C}$ | 3.6 V | -2 | 0.3 | $2^{(2)}$ | nA |
| (ON) |  |  |  | Full |  | -20 |  | 20 |  |
| Digital Control Inputs (IN1, IN2) ${ }^{(3)}$ |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Input logic high |  |  | Full |  | 2 |  | 5.5 | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Input logic low |  |  | Full |  | 0 |  | 0.8 | V |
| $\mathrm{I}_{\mathrm{IH}}, \mathrm{I}_{\mathrm{IL}}$ | Input leakage current | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 3.6 V | -2 | 0.3 | 2 | nA |
|  |  |  |  | Full |  | -20 |  | 20 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
(2) Not tested in production.
(3) All unused digital inputs of the device must be held at $\mathrm{V}_{+}$or GND to ensure proper device operation. Refer to the Tl application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## Electrical Characteristics: 3.3-V Supply (continued)

$\mathrm{V}_{+}=3 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{+}$ | MIN TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |
| $Q_{C}$ | Charge injection | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\begin{aligned} & C_{\mathrm{L}}=1 \mathrm{nF}, \\ & \text { see Figure } 19 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V | 6 |  | pC |
| $\mathrm{C}_{\text {NO(OFF) }}$ | NO OFF capacitance | $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{+}$or GND, Switch OFF, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.3 V | 19.5 |  | pF |
| $\mathrm{C}_{\text {COM(OFF) }}$ | COM <br> OFF capacitance | $V_{\text {COM }}=V_{+}$or GND, Switch OFF, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.3 V | 18.5 |  | pF |
| $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | NO ON capacitance | $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{+} \text {or GND, }$ <br> Switch ON, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.3 V | 36 |  | pF |
| $\mathrm{C}_{\text {COM(ON) }}$ | COM ON capacitance | $V_{\text {COM }}=V_{+}$or GND, Switch ON, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.3 V | 36 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.3 V | 2 |  | pF |
| BW | Bandwidth | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \text { Switch ON, } \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V | 150 |  | MHz |
| $\mathrm{O}_{\text {ISO }}$ | OFF isolation | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | Switch OFF, see Figure 17 | $25^{\circ} \mathrm{C}$ | 3.3 V | -62 |  | dB |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | Switch ON, see Figure 18 | $25^{\circ} \mathrm{C}$ | 3.3 V | -85 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \end{aligned}$ | $\begin{aligned} & f=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz}, \\ & \text { see Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V | 0.01\% |  |  |
| Supply |  |  |  |  |  |  |  |  |
| $I_{+}$ | Positive supply current | $\mathrm{V}_{\mathrm{l}}=\mathrm{V}_{+}$or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 3.6 V | 0.001 | 0.05 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  | 0.3 |  |

### 6.7 Electrical Characteristics: 2.5-V Supply

$\mathrm{V}_{+}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\text {COM }}, \mathrm{V}_{\text {NO }}$ | Analog signal range |  |  |  |  | 0 |  | $\mathrm{V}_{+}$ | V |
| $\mathrm{r}_{\text {peak }}$ | Peak ON resistance | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 1.8 | 2.4 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 2.6 |  |
| $\mathrm{r}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 1.2 | 2.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 2.4 |  |
|  | ON-state |  |  | $25^{\circ} \mathrm{C}$ |  |  | 0.04 | 0.15 |  |
| $\Delta r_{\text {on }}$ | resistance <br> match between channels | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1.8 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | Full | 2.3 V |  |  | 0.15 | $\Omega$ |
| $\mathrm{r}_{\text {on(flat) }}$ | ON-state resistance flatness | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 0.7 |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=1.8 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ |  |  | 0.4 | 0.6 |  |
|  |  |  |  | Full |  |  |  | 0.6 |  |
|  | NO OFF leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=0.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=2.3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=0.5 \mathrm{~V}, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 2.7 V | -5 | 0.3 | $5^{(2)}$ |  |
| $\mathrm{I}_{\text {NO(OFF) }}$ |  |  |  | Full |  | -50 |  | 50 | nA |
| $\mathrm{I}_{\text {No(PWROFF) }}$ |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=0 \text { to } 2.7 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=2.7 \mathrm{~V} \text { to } 0, \end{aligned}$ | Switch OFF, <br> see Figure 12 | $25^{\circ} \mathrm{C}$ | 0 V | -2 | 0.05 | $2^{(2)}$ | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  | -15 |  | 15 |  |

[^1]
## Electrical Characteristics: 2.5-V Supply (continued)

$\mathrm{V}_{+}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\mathrm{A}}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {Com(OFF) }}$ | COM OFF leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=0.5 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}}=0.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=2.3 \mathrm{~V}, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 2.7 V | -5 | 0.3 | $5^{(2)}$ |  |
|  |  |  |  | Full |  | -50 |  | 50 | nA |
| ICOM(PWROFF) |  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=0 \text { to } 2.7 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{NO}}=2.7 \mathrm{~V} \text { to } 0, \end{aligned}$ | Switch OFF, see Figure 12 | $25^{\circ} \mathrm{C}$ | 0 V | -2 | 0.05 | $2^{(2)}$ | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  | -15 |  | 15 |  |
| $I_{\mathrm{NO}(\mathrm{ON})}$ | NO ON leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=0.5 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\mathrm{Open}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\text { Open, } \end{aligned}$ | Switch ON, see Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V | -2 | 0.3 | $2^{(2)}$ | nA |
|  |  |  |  | Full |  | -20 |  | 20 |  |
|  |  | $\mathrm{V}_{\text {COM }}=0.5 \mathrm{~V},$ |  | $25^{\circ} \mathrm{C}$ |  | -2 | 0.3 | $2^{(2)}$ |  |
| $\mathrm{I}_{\text {COM (ON) }}$ | COM <br> ON leakage current | $\mathrm{V}_{\mathrm{NO}}=$ Open, <br> or $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{NO}}=\text { Open, } \end{aligned}$ | Switch ON, see Figure 13 | Full | 2.7 V | -20 |  | 20 | nA |
| Digital Control Inputs (IN1, IN2) |  |  |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Input logic high |  |  | Full |  | 1.8 |  | 5.5 | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Input logic low |  |  | Full |  | 0 |  | 0.6 | V |
| $\mathrm{I}_{\mathrm{HH}}, \mathrm{I}_{\text {IL }}$ | Input leakage current | $\mathrm{V}_{1}=5.5 \mathrm{~V}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 2.7 V | -2 | 0.3 | 2 | nA |
|  |  |  |  | Full |  | -20 |  | 20 |  |
| Dynamic |  |  |  |  |  |  |  |  |  |
| $Q_{C}$ | Charge injection | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\begin{aligned} & C_{L}=1 \mathrm{nF}, \\ & \text { see Figure } 19 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 4 |  | pC |
| $\mathrm{C}_{\text {NO(OFF) }}$ | NO OFF capacitance | $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{+}$or GND, Switch OFF, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 19.5 |  | pF |
| $\mathrm{C}_{\text {COM (OFF) }}$ | COM OFF capacitance | $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}$or GND, Switch OFF, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 18.5 |  | pF |
| $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | NO <br> ON <br> capacitance | $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{+}$or GND, Switch ON, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 36.5 |  | pF |
| $\mathrm{C}_{\text {COM(ON) }}$ | COM <br> ON <br> capacitance | $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}$or GND, Switch ON, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 36.5 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 2 |  | pF |
| BW | Bandwidth | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \text { Switch ON, } \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 150 |  | MHz |
| $\mathrm{O}_{\text {ISO }}$ | OFF isolation | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | Switch OFF, see Figure 17 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | -62 |  | dB |
| $\mathrm{X}_{\text {TALK }}$ | Crosstalk | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | Switch ON, see Figure 18 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | -85 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \end{aligned}$ | $\mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz},$ see Figure 20 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 0.02\% |  |  |
| Supply |  |  |  |  |  |  |  |  |  |
| $I_{+}$ | Positive supply current | $\mathrm{V}_{1}=\mathrm{V}_{+} \text {or GND, }$ | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | $2.7 \mathrm{~V}$ |  | 0.001 | 0.02 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  |  | 0.25 |  |

TS5A23166
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### 6.8 Electrical Characteristics: 1.8-V Supply

$\mathrm{V}_{+}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER | TEST CONDITIONS | $T_{A}$ | $\mathbf{V}_{+}$ | MIN | TYP |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |


| $\mathrm{V}_{\text {COM }}, \mathrm{V}_{\text {NO }}$ | Analog signal range |  |  |  |  | 0 | $\mathrm{V}_{+}$ | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{r}_{\text {peak }}$ | Peak ON resistance | $\begin{aligned} & 0 \leq \mathrm{V}_{\mathrm{NO}} \leq \mathrm{V}_{+}, \\ & \mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 1.65 V | 4.2 | 25 | $\Omega$ |
|  |  |  |  | Full |  |  | 30 |  |
| $\mathrm{r}_{\text {on }}$ | ON-state resistance | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}}=0.6 \mathrm{~V}, 1.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA}, \end{aligned}$ | Switch ON, see Figure 11 | $25^{\circ} \mathrm{C}$ | 1.65 V | 1.6 | 3.9 | $\Omega$ |
|  |  |  |  | Full |  |  | 4 |  |


|  | ON-state <br> resistance <br> match <br> between <br> channels |
| :--- | :--- |
| $r_{\text {on }}$ |  |
|  | ON-state <br> resistance <br> flatness |
|  |  |


|  |  |
| :--- | :--- |
| $I_{\text {NO(OFF) }}$ | NO <br> OFF leakage <br> current |
| $\mathrm{I}_{\text {NO(PWROFF) }}$ |  |

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## Electrical Characteristics: 1.8-V Supply (continued)

$\mathrm{V}_{+}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{+}$ | MIN TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {COM(ON) }}$ | COM <br> ON capacitance | $\mathrm{V}_{\text {Сом }}=\mathrm{V}_{+}$or GND, Switch ON, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 1.8 V | 36.5 |  | pF |
| $\mathrm{C}_{1}$ | Digital input capacitance | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{+}$or GND, | See Figure 14 | $25^{\circ} \mathrm{C}$ | 1.8 V | 2 |  | pF |
| BW | Bandwidth | $\mathrm{R}_{\mathrm{L}}=50 \Omega,$ Switch ON, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 1.8 V | 150 |  | MHz |
| $\mathrm{O}_{\text {ISo }}$ | OFF isolation | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | Switch OFF, see Figure 17 | $25^{\circ} \mathrm{C}$ | 1.8 V | -62 |  | dB |
| THD | Total harmonic distortion | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \end{aligned}$ | $\mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz},$ see Figure 20 | $25^{\circ} \mathrm{C}$ | 1.8 V | 0.055\% |  |  |
| Supply |  |  |  |  |  |  |  |  |
| $I_{+}$ | Positive supply current | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 1.95 V | 0.001 | 0.01 | $\mu \mathrm{A}$ |
|  |  |  |  | Full |  |  | 0.15 |  |

### 6.9 Switching Characteristics: 5-V Supply

$\mathrm{V}_{+}=4.5 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

|  | PARAMETER | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| ton | Turnon time | $\begin{aligned} & \mathrm{V}_{\text {COM }}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & C_{L}=35 \mathrm{pF}, \\ & \text { see Figure } 15 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 5 V | 1 | 4.5 | 7.5 | ns |
|  |  |  |  | Full | 4.5 V to 5.5 V | 1 |  | 9 |  |
| $\mathrm{t}_{\text {OFF }}$ | Turnoff time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ <br> see Figure 15 | $25^{\circ} \mathrm{C}$ | 5 V | 4.5 | 8 | 11 | ns |
|  |  |  |  | Full | 4.5 V to 5.5 V | 3.5 |  | 13 |  |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

### 6.10 Switching Characteristics: 3.3-V Supply

$\mathrm{V}_{+}=3 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}, \\ & \text { see Figure } 15 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V | 1.5 | 5 | 9.5 | ns |
| $\mathrm{t}_{\mathrm{ON}} \quad$ Turnon time |  |  | Full | $\begin{aligned} & 3 \mathrm{~V} \text { to } \\ & 3.6 \mathrm{~V} \end{aligned}$ | 1 |  | 10 |  |
|  | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & C_{L}=35 \mathrm{pF}, \\ & \text { see Figure } 15 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V | 4.5 | 8.5 | 11 | ns |
| $\mathrm{t}_{\text {OFF }} \quad$ Turnoff time |  |  | Full | $\begin{aligned} & 3 \mathrm{~V} \text { to } \\ & 3.6 \mathrm{~V} \end{aligned}$ | 3 |  | 12.5 |  |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

### 6.11 Switching Characteristics: 2.5-V Supply

$\mathrm{V}_{+}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

|  | PARAMETER | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| $\mathrm{t}_{\mathrm{ON}}$ | Turnon time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 15 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V | 2 | 6 | 10 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \mathrm{~V} \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ | 1 |  | 12 |  |
| toff | Turnoff time | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$$\text { see Figure } 15$ | $25^{\circ} \mathrm{C}$ | 2.5 V | 4.5 | 8 | 12.5 | ns |
|  |  |  |  | Full | $\begin{gathered} 2.3 \mathrm{~V} \text { to } \\ 2.7 \mathrm{~V} \end{gathered}$ | 3 |  | 15 |  |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

### 6.12 Switching Characteristics: 1.8-V Supply

| PARAMETER | TEST CONDITIONS |  | T ${ }_{\text {A }}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |
| Turnon time | $\begin{aligned} & \mathrm{V}_{\text {COM }}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \\ & \text { see Figure } 15 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 1.8 V | 3 | 9 | 18 | ns |
|  |  |  | Full | $\begin{gathered} 1.65 \mathrm{~V} \text { to } \\ 1.95 \mathrm{~V} \end{gathered}$ | 1 |  | 20 |  |
|  |  |  | $25^{\circ} \mathrm{C}$ | 1.8 V | 5 | 10 | 15.5 |  |
| $\mathrm{t}_{\text {OFF }} \quad$ Turnoff time | $\begin{aligned} & V_{\text {COM }}=V_{+}, \\ & R_{L}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$, <br> see Figure 15 | Full | $\begin{gathered} 1.65 \mathrm{~V} \text { to } \\ 1.95 \mathrm{~V} \end{gathered}$ | 4 |  | 18.5 | ns |

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

### 6.13 Typical Characteristics



Figure 1. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}$


Figure 3. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}\left(\mathrm{V}_{+}=5 \mathrm{~V}\right)$


Figure 5. Charge Injection $\left(Q_{C}\right)$ vs $\mathrm{V}_{\text {com }}$


Figure 2. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}\left(\mathrm{V}_{+}=3.3 \mathrm{~V}\right)$


Figure 4. Leakage Current vs Temperature ( $\mathrm{V}_{+}=5.5 \mathrm{~V}$ )


Figure 6. $\mathrm{t}_{\mathrm{ON}}$ and $\mathrm{t}_{\text {OFF }}$ vs Supply Voltage

## Typical Characteristics (continued)



Figure 7. $\mathrm{t}_{\mathrm{ON}}$ and $\mathrm{t}_{\mathrm{OFF}}$ vs Temperature $\left(\mathrm{V}_{+}=5 \mathrm{~V}\right)$


Figure 9. OFF Isolation and Crosstalk ( $\mathrm{V}_{+}=5 \mathrm{~V}$ )


Figure 8. Bandwidth ( $\mathbf{V}_{+}=5 \mathrm{~V}$ )


Figure 10. Total Harmonic Distortion vs Frequency

## 7 Parameter Measurement Information



Figure 11. ON-State Resistance ( $\mathrm{r}_{\mathrm{on}}$ )


Figure 12. OFF-State Leakage Current (ICOM(OFF), $\left.I_{\mathrm{NC}(\mathrm{OFF})}, \mathrm{I}_{\mathrm{COM(PWROFF})}, \mathrm{I}_{\mathrm{NC}(\mathrm{PWR}(\mathrm{FF})}\right)$


Figure 13. ON-State Leakage Current (ICOM(ON), $\left.\mathrm{I}_{\mathrm{NC}(\mathrm{ON})}\right)$

## Parameter Measurement Information (continued)



$$
\begin{aligned}
& V_{\text {BIAS }}=V_{+} \text {or GND } \\
& V_{I}=V_{+} \text {or GND } \\
& \text { Capacitance is measured at NO, } \\
& \text { COM, and IN inputs during ON } \\
& \text { and OFF conditions. }
\end{aligned}
$$

Figure 14. Capacitance ( $\left.\mathrm{C}_{\mathrm{l}}, \mathrm{C}_{\mathrm{COM}(\mathrm{OFF})}, \mathrm{C}_{\mathrm{COM}(\mathrm{ON})}, \mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}, \mathrm{C}_{\mathrm{NC}(\mathrm{ON})}\right)$


Figure 15. Turnon ( $\mathrm{t}_{\mathrm{ON}}$ ) and Turnoff Time ( $\mathrm{t}_{\mathrm{OFF}}$ )


Figure 16. Bandwidth (BW)

## Parameter Measurement Information (continued)



> | Channel OFF: NO to COM |
| :--- |
| $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{+}$or GND |
|  |
| Network Analyzer Setup |
| Source Power $=0 \mathrm{dBm}$ |
| (632-mV P-P at $50-\Omega \mathrm{load}$ ) |
| DC Bias $=350 \mathrm{mV}$ |

Figure 17. OFF Isolation ( $\mathrm{O}_{\mathrm{ISo}}$ )


Figure 18. Crosstalk ( $\mathrm{X}_{\text {TALK }}$ )

(1) $C_{L}$ includes probe and jig capacitance.
(2) All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.

Figure 19. Charge Injection $\left(Q_{C}\right)$

## Parameter Measurement Information (continued)


(1) $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 20. Total Harmonic Distortion (THD)

## 8 Detailed Description

### 8.1 Overview

The TS5A23166 is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V . The device offers a low ON -state resistance. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications. Table 2 shows the descriptions of each parameter specified in the datasheet.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

Tolerant control inputs allow 5-V logic levels to be present on the IN pin at any value of $\mathrm{V}_{\mathrm{CC}}$. Low ON -resistance allows minimal signal distortion through device.

### 8.4 Device Functional Modes

Table 1 shows the functional modes for TS5A23166.
Table 1. Function Table

| IN | NO TO COM, <br> COM TO NO |
| :---: | :---: |
| L | OFF |
| $H$ | ON |

## 9 Application and Implementation

## NOTE

Information in the following applications sections is not part of the Tl component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The TS5A23166 dual SPST analog switch is a basic component that could be used in any electrical system design. One example application is a gain selector, which is described in the Typical Application section.

### 9.2 Typical Application



Figure 21. Gain-Control Circuit for OP Amplifier

### 9.2.1 Design Requirements

By selecting values of R1 and R2, such that $R x \gg r_{o n(x)}$, $r_{\text {on }}$ of TS5A23166 can be ignored. The gain of op amp can be calculated as follow:

$$
\begin{align*}
& \mathrm{Vo} / \mathrm{VI}=1+\mathrm{R} \| / \mathrm{R} 3  \tag{1}\\
& \mathrm{R}\left\|=\left(\mathrm{R} 1+\mathrm{r}_{\text {on(1) }}\right)\right\|\left(\mathrm{R} 2+\mathrm{r}_{\text {on(2) }}\right) \tag{2}
\end{align*}
$$

### 9.2.2 Detailed Design Procedure

Place a switch in series with the input of the op amp. Because the op amp input impedance is very large, a switch on $r_{\text {on(1) }}$ is irrelevant.

## Typical Application (continued)

### 9.2.3 Application Curve



Figure 22. Power-Supply Current vs Temperature ( $\mathrm{V}_{+}=5 \mathrm{~V}$ )

## 10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Recommended Operating Conditions.
Each $\mathrm{V}_{\mathrm{CC}}$ terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a $0.1-\mu \mathrm{F}$ bypass capacitor is recommended. If there are multiple pins labeled $\mathrm{V}_{\mathrm{cc}}$, then a $0.01-\mu \mathrm{F}$ or $0.022-\mu \mathrm{F}$ capacitor is recommended for each $\mathrm{V}_{\mathrm{CC}}$ because the VCC pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example $\mathrm{V}_{\mathrm{Cc}}$ and $\mathrm{V}_{\mathrm{DD}}$, a $0.1-\mu \mathrm{F}$ bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. $0.1-\mu \mathrm{F}$ and $1-\mu \mathrm{F}$ capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 11 Layout

### 11.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a $90^{\circ}$ angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace - resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Figure 23 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

### 11.2 Layout Example

WORST

BETTER

w

BEST


Figure 23. Trace Example

## 12 Device and Documentation Support

### 12.1 Device Support

### 12.1.1 Device Nomenclature

Table 2. Parameter Description

| SYMBOL | DESCRIPTION |
| :---: | :---: |
| $\mathrm{V}_{\text {COM }}$ | Voltage at COM |
| $\mathrm{V}_{\mathrm{NO}}$ | Voltage at NO |
| $\mathrm{r}_{\text {on }}$ | Resistance between COM and NO ports when the channel is ON |
| $\mathrm{r}_{\text {peak }}$ | Peak on-state resistance over a specified voltage range |
| $\mathrm{r}_{\text {on(flat) }}$ | Difference between the maximum and minimum value of $r_{\text {on }}$ in a channel over the specified range of conditions |
| $\mathrm{I}_{\text {NO(OFF) }}$ | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF-state under worst-case input and output conditions |
| $\mathrm{I}_{\mathrm{NO} \text { (PWROFF) }}$ | Leakage current measured at the NO port during the power-down condition, $\mathrm{V}_{+}=0$ |
| $\mathrm{I}_{\text {COM (OFF) }}$ | Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the OFF-state under worstcase input and output conditions |
| $\mathrm{I}_{\text {COM(PWROFF) }}$ | Leakage current measured at the COM port during the power-down condition, $\mathrm{V}_{+}=0$ |
| $\mathrm{l}_{\mathrm{NO}(\mathrm{ON})}$ | Leakage current measured at the NO port, with the corresponding channel ( NO to COM ) in the ON-state and the output (COM) open |
| $\mathrm{I}_{\text {COM }}(\mathrm{ON})$ | Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the ON-state and the output (NO) open |
| $\mathrm{V}_{\mathrm{IH}}$ | Minimum input voltage for logic high for the control input (IN) |
| $\mathrm{V}_{\text {IL }}$ | Maximum input voltage for logic low for the control input (IN) |
| $\mathrm{V}_{1}$ | Voltage at the control input (IN) |
| $\mathrm{I}_{\text {IH }}, \mathrm{I}_{\text {IL }}$ | Leakage current measured at the control input (IN) |
| ton | Turnon time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON. |
| toff | Turnoff time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO ) signal when the switch is turning OFF. |
| $Q_{C}$ | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $\mathrm{Q}_{\mathrm{C}}=\mathrm{C}_{\mathrm{L}} \times \Delta \mathrm{V}_{\mathrm{COM}}, \mathrm{C}_{\mathrm{L}}$ is the load capacitance, and $\Delta \mathrm{V}_{\mathrm{COM}}$ is the change in analog output voltage. |
| $\mathrm{C}_{\mathrm{NO} \text { (OFF) }}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF |
| $\mathrm{C}_{\text {COM (OFF) }}$ | Capacitance at the COM port when the corresponding channel (COM to NO) is OFF |
| $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | Capacitance at the NO port when the corresponding channel (NO to COM) is ON |
| $\mathrm{C}_{\text {COM(ON) }}$ | Capacitance at the COM port when the corresponding channel (COM to NO) is ON |
| $\mathrm{C}_{1}$ | Capacitance of control input (IN) |
| O ISO | OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NO to COM) in the OFF state. |
| BW | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain. |
| THD | Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic. |
| $\mathrm{I}_{+}$ | Static power-supply current with the control (IN) pin at $\mathrm{V}_{+}$or GND |

### 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on Alert me to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 Community Resources

TI E2E ${ }^{\text {TM }}$ support forums are an engineer's go-to source for fast, verified answers and design help - straight from the experts. Search existing answers or ask your own question to get the quick design help you need.
Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect Tl's views; see Tl's Terms of Use.

### 12.4 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

### 12.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.6 Glossary

SLYZ022 - TI Glossary.
This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead finish/ Ball material <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A23166DCUR | ACTIVE | VSSOP | DCU | 8 | 3000 | RoHS \& Green | NIPDAU \| SN | Level-1-260C-UNLIM | -40 to 85 | (AM, JAMQ, JAMR) JZ | Samples |
| TS5A23166DCURG4 | ACTIVE | VSSOP | DCU | 8 | 3000 | RoHS \& Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | JAMR | Samples |
| TS5A23166YZPR | ACTIVE | DSBGA | YZP | 8 | 3000 | RoHS \& Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | JMN | Samples |
| TS5A23166YZTR | ACTIVE | DSBGA | YZT | 8 | 3000 | RoHS \& Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | JMN | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the $<=1000$ ppm threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a " $\sim$ " will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM
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## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> $\mathbf{W 1 ( m m )}$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | $\mathbf{W}$ <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 180.0 | 9.0 | 2.25 | 3.4 | 1.0 | 4.0 | 8.0 | Q3 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 178.0 | 9.5 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| TS5A23166DCURG4 | VSSOP | DCU | 8 | 3000 | 180.0 | 8.4 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| TS5A23166YZPR | DSBGA | YZP | 8 | 3000 | 178.0 | 9.2 | 1.02 | 2.02 | 0.63 | 4.0 | 8.0 | Q1 |
| TS5A23166YZTR | DSBGA | YZT | 8 | 3000 | 178.0 | 9.2 | 1.02 | 2.02 | 0.75 | 4.0 | 8.0 | Q1 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 182.0 | 182.0 | 20.0 |
| TS5A23166DCUR | VSSOP | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A23166DCURG4 | VSSOP | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| TS5A23166YZPR | DSBGA | YZP | 8 | 3000 | 220.0 | 220.0 | 35.0 |
| TS5A23166YZTR | DSBGA | YZT | 8 | 3000 | 220.0 | 220.0 | 35.0 |

YZT (R-XBGA-N8)


NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. NanoFree ${ }^{T M}$ package configuration.

NanoFree is a trademark of Texas Instruments.


DETAIL A TYPICAL

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-187 variation CA.


NOTES: (continued)
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

NOTES: (continued)
7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.


NOTES: (continued)
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).


NOTES: (continued)
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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[^0]:    (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
    (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
    (3) All voltages are with respect to ground, unless otherwise specified.
    (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
    (5) This value is limited to 5.5 V maximum.
    (6) Pulse at 1 -ms duration $<10 \%$ duty cycle.

[^1]:    (1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
    (2) Not tested in production.

